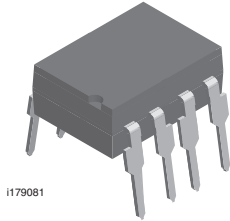
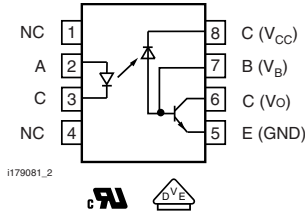


High Speed Optocoupler, 1 MBd, Photodiode with Transistor Output



i179081



i179081_2



FEATURES

- Isolation test voltages: 5300 V_{RMS}
- TTL compatible
- High bit rates: 1 Mbit/s
- High common-mode interference immunity
- Bandwidth 2 MHz
- Open-collector output
- External base wiring possible
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


**RoHS
COMPLIANT**

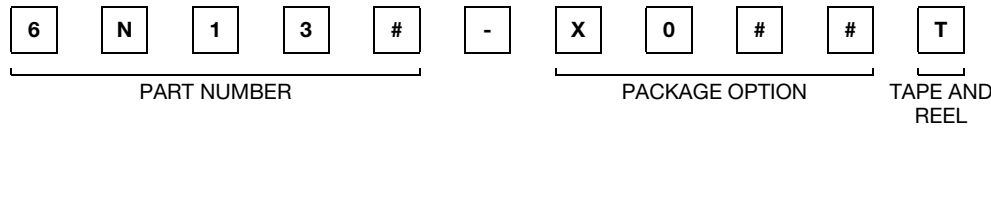
DESCRIPTION

The 6N135 and 6N136 are optocouplers with a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector which consists of a photo diode and a high-speed transistor in a DIP-8 plastic package. Signals can be transmitted between two electrically separated circuits up to frequencies of 2 MHz. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- CSA 93751

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)	
UL	≥ 7	≥ 19
DIP-8	6N135	6N136
DIP-8, 400 mil, option 6	-	6N136-X006
SMD-8, option 7	6N135-X007T ⁽¹⁾	6N136-X007T ⁽¹⁾
SMD-8, option 9	-	6N136-X009T ⁽¹⁾
VDE, UL	≥ 7	≥ 19
DIP-8	-	6N136-X001
DIP-8, 400 mil, option 6	-	6N136-X016
SMD-8, option 7	6N135-X017T ⁽¹⁾	6N136-X019T

Note

⁽¹⁾ Also available in tubes; do not add T to end

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	5	V
Forward current		I _F	25	mA
Peak forward current	t = 1 ms, duty cycle 50 %	I _{FSM}	50	mA
Maximum surge forward current	t ≤ 1 μs, 300 pulses/s		1	A
Thermal resistance		R _{th}	700	K/W
Power dissipation	T _{amb} = 70 °C	P _{diss}	45	mW

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
OUTPUT				
Supply voltage		V_S	- 0.5 to 15	V
Output voltage		V_O	- 0.5 to 15	V
Emitter base voltage		V_{EBO}	5	V
Output current		I_O	8	mA
Maximum output current			16	mA
Base current		I_B	5	mA
Thermal resistance			300	K/W
Power dissipation	$T_{amb} = 70\text{ }^{\circ}\text{C}$	P_{diss}	100	mW
COUPLER				
Isolation test voltage between emitter and detector	$t = 1\text{ s}$	V_{ISO}	5300	V_{RMS}
Pollution degree (DIN VDE 0109)			2	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range		T_{stg}	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	max. $\leq 10\text{ s}$, dip soldering $\geq 0.5\text{ mm}$ from case bottom	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 1.6\text{ mA}$		V_F		1.6	1.9	V
Breakdown voltage	$I_R = 10\text{ }\mu\text{A}$		V_{BR}	5			V
Reverse current	$V_R = 5\text{ V}$		I_R		0.5	10	μA
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		C_O		125		pF
Temperature coefficient, forward voltage	$I_F = 1.6\text{ mA}$		$\Delta V_F/\Delta T_A$		- 1.7		mV/ $^{\circ}\text{C}$
OUTPUT							
Logic low supply current	$I_F = 1.6\text{ mA}, V_O = \text{open}, V_{CC} = 15\text{ V}$		I_{CCL}		150		μA
Logic high supply current	$I_F = 0\text{ mA}, V_O = \text{open}, V_{CC} = 15\text{ V}$		I_{CCH}		0.01	1	μA
Output voltage, output low	$I_F = 16\text{ mA}, I_O = 1.1\text{ mA}, V_{CC} = 4.5\text{ V}$	6N135	V_{OL}		0.1	0.4	V
	$I_F = 16\text{ mA}, I_O = 2.4\text{ mA}, V_{CC} = 4.5\text{ V}$	6N136	V_{OL}		0.1	0.4	V
Output current, output high	$I_F = 0\text{ mA}, V_O = V_{CC} = 5.5\text{ V}$		I_{OH}		3	500	nA
	$I_F = 0\text{ mA}, V_O = V_{CC} = 15\text{ V}$		I_{OH}		0.01	1	μA
COUPLER							
Capacitance (input to output)	$f = 1\text{ MHz}$		C_{IO}		0.6		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 16 \text{ mA}, V_O = 0.4 \text{ V}, V_{CC} = 4.5 \text{ V}$	6N135	CTR	7	16		%
		6N136	CTR	19	35		%
	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V}, V_{CC} = 4.5 \text{ V}$	6N135	CTR	5			%
		6N136	CTR	15			%

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High to low	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	t_{PHL}		0.3	1.5	μs
	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	t_{PHL}		0.2	0.8	μs
Low to high	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	t_{PLH}		0.3	1.5	μs
	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	t_{PLH}		0.2	0.8	μs

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High	$I_F = 0 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	$ CM_H $		1000		$\text{V}/\mu\text{s}$
	$I_F = 0 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	$ CM_H $		1000		$\text{V}/\mu\text{s}$
Low	$I_F = 16 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	$ CM_L $		1000		$\text{V}/\mu\text{s}$
	$I_F = 16 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	$ CM_L $		1000		$\text{V}/\mu\text{s}$

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V_{IOTM}			8000			V	
V_{IORM}			890			V	
P_{SO}					500	mW	
I_{SI}					300	mA	
T_{SI}					175	$^{\circ}\text{C}$	
Creepage distance	Standard DIP-8		7			mm	
Clearance distance	Standard DIP-8		7			mm	
Creepage distance	400 mil DIP-8		8			mm	
Clearance distance	400 mil DIP-8		8			mm	

Note

- As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

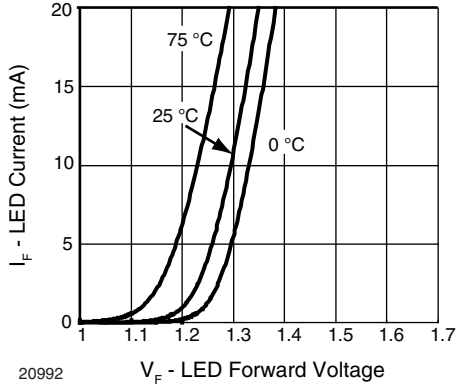


Fig. 1 - LED Forward Current vs. Forward Voltage

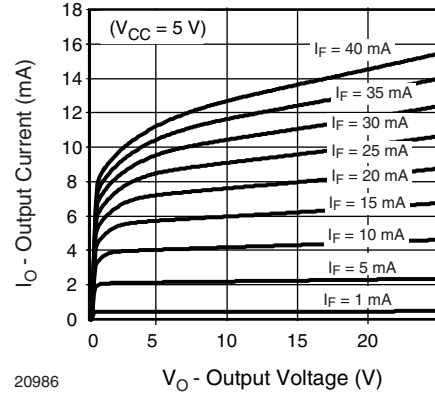


Fig. 4 - Output Current vs. Output Voltage

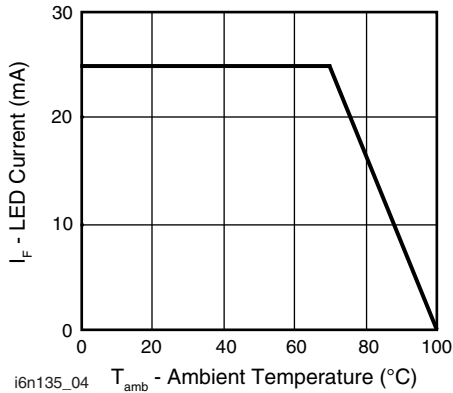


Fig. 2 - Permissible Forward LED Current vs. Temperature

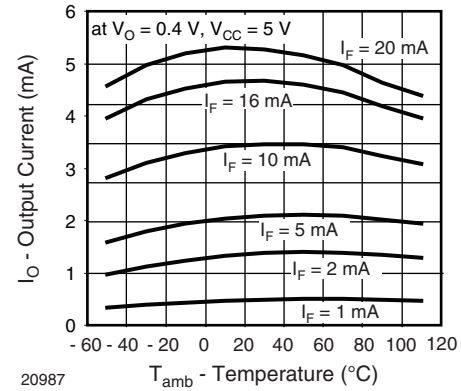


Fig. 5 - Output Current vs. Temperature

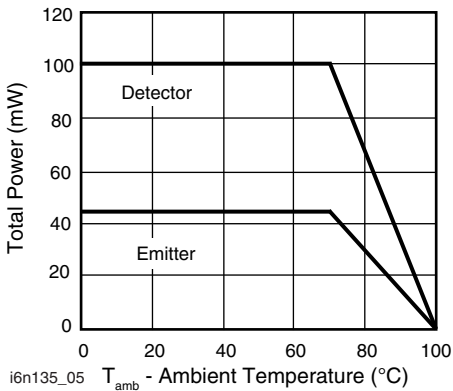


Fig. 3 - Permissible Power Dissipation vs. Temperature

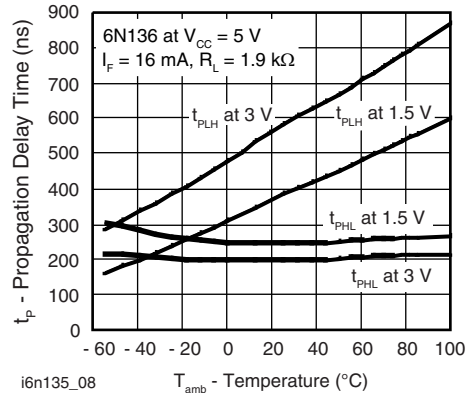


Fig. 6 - Propagation Delay vs. Ambient Temperature

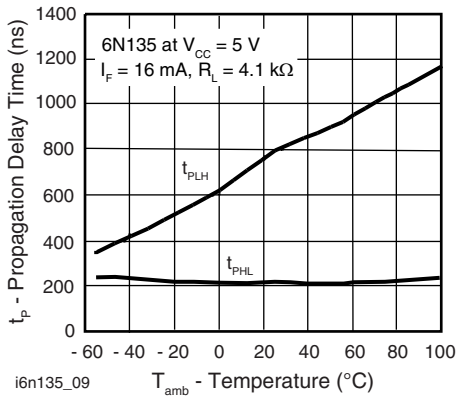


Fig. 7 - Propagation Delay vs. Ambient Temperature

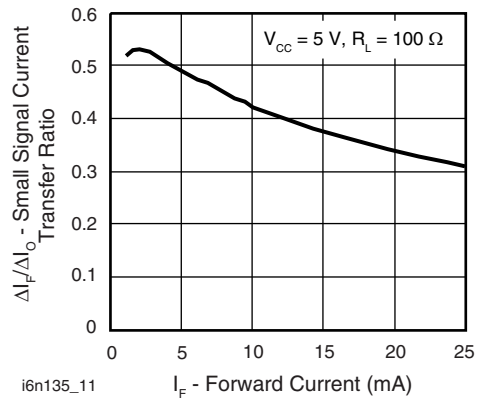


Fig. 9 - Small Signal Current Transfer Ratio vs. Quiescent Input Current

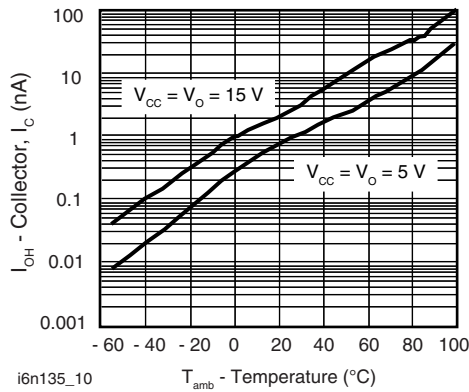


Fig. 8 - Logic High Output Current vs. Temperature

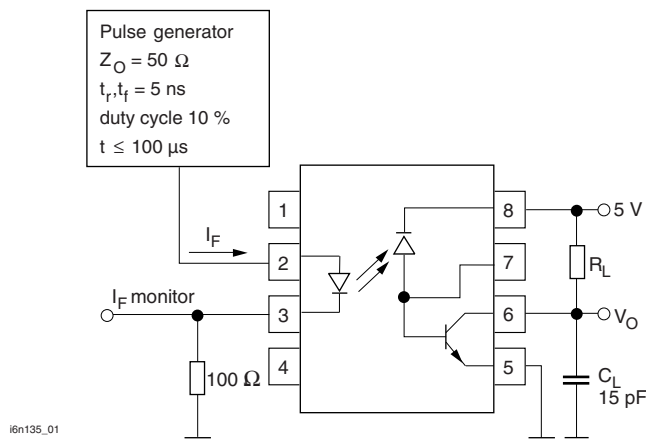
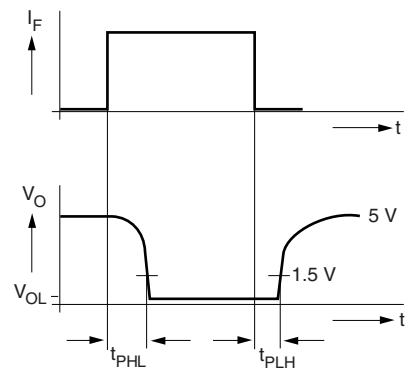


Fig. 10 - Switching Times



6N135, 6N136

Vishay Semiconductors High Speed Optocoupler, 1 MBd,
Photodiode with Transistor Output

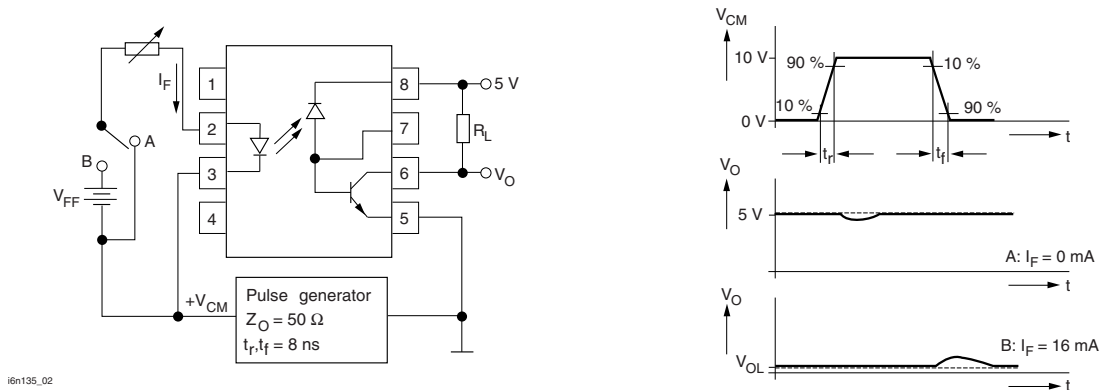
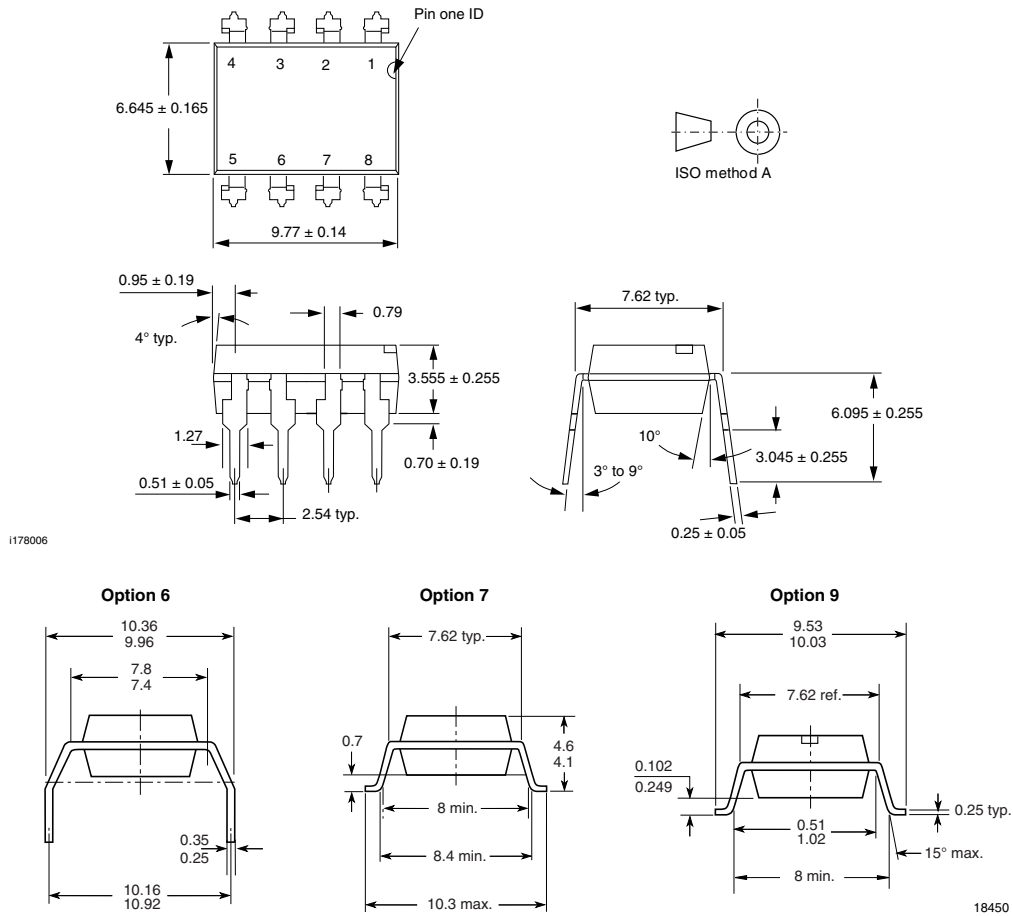
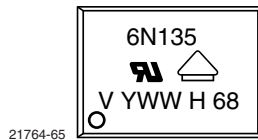


Fig. 11 - Common-Mode Interference Immunity

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING



21764-65



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